Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

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Email & Skype: info@chipsmall.com Web: www.chipsmall.com
Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China

N-Channel Power MOSFET

650V, 7A, 1.45Ω

FEATURES

- Low C_{rss} typical @ 15pF (Typ.)
- 100% Avalanche Tested
- Pb-free plating
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition
-

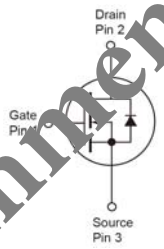
APPLICATION

- Power Supply
- Lighting

KEY PERFORMANCE PARAMETERS		
PARAMETER	**VALUE**	**UNIT**
V_{DS}	650	V
$R_{DS(on)}$ (max)	1.45	Ω
Q_g	27.8	nC

Pb-Free RoHS COMPLIANT HALOGEN FREE

ITO-220



ABSOLUTE MAXIMUM RATINGS (T_A = 25°C unless otherwise noted)				
PARAMETER		**SYMBOL**	**Limit**	**UNIT**
Drain-Source Voltage		V_{DS}	650	V
Gate-Source Voltage		V_{GS}	±30	V
Continuous Drain Current (Note 1)	T_C = 25°C	I_D	7	A
	T_C = 100°C		4.2	
Pulsed Drain Current (Note 2)		I_{DM}	28	A
Total Power Dissipation @ T_C = 25°C		P_{DTOT}	40	W
Single Pulsed Avalanche Energy (Note 3)		E_{AS}	150	mJ
Single Pulsed Avalanche Current (Note 3)		I_{AS}	5	A
Operating Junction and Storage Temperature Range		T_J, T_{STG}	- 55 to +150	°C

THERMAL PERFORMANCE			
PARAMETER	**SYMBOL**	**Limit**	**UNIT**
Junction to Case Thermal Resistance	$R_{\Theta JC}$	3.1	°C/W
Junction to Ambient Thermal Resistance	$R_{\Theta JA}$	65	°C/W

Notes: $R_{\Theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistances. The case thermal reference is defined at the solder mounting surface of the drain pins. $R_{\Theta JA}$ is guaranteed by design while $R_{\Theta CA}$ is determined by the user's board design. $R_{\Theta JA}$ shown below for single device operation on FR-4 PCB with minimum recommended footprint in still air.

ELECTRICAL SPECIFICATIONS (T_A = 25°C unless otherwise noted)						
PARAMETER	**CONDITIONS**	**SYMBOL**	**MIN**	**TYP**	**MAX**	**UNIT**
Static (Note 4)						
Drain-Source Breakdown Voltage	V_{GS} = 0V, I_D = 250μA	BV_{DSS}	650	--	--	V
Gate Threshold Voltage	V_{DS} = V_{GS}, I_D = 250μA	$V_{GS(TH)}$	2.0	3.0	4.0	V
Gate Body Leakage	V_{GS} = ±30V, V_{DS} = 0V	I_{GSS}	--	--	±100	nA
Zero Gate Voltage Drain Current	V_{DS} = 650V, V_{GS} = 0V	I_{DSS}	--	--	1	μA
Drain-Source On-State Resistance	V_{GS} = 10V, I_D = 3.0A	$R_{DS(on)}$	--	1.2	1.45	Ω
Dynamic (Note 5)						
Total Gate Charge	V_{DS} = 480V, I_D = 6.0A, V_{GS} = 10V	Q_g	--	27.8	--	nC
Gate-Source Charge		Q_{gs}	--	5.7	--	
Gate-Drain Charge		Q_{gd}	--	8.8	--	
Input Capacitance	V_{DS} = 25V, V_{GS} = 0V, f = 1.0MHz	C_{iss}	--	1406	--	pF
Output Capacitance		C_{oss}	--	114	--	
Reverse Transfer Capacitance		C_{rss}	--	15	--	
Gate Resistance	F = 1MHz, open drain	R_g	--	1.5	--	Ω
Switching (Note 6)						
Turn-On Delay Time	V_{DD} = 300V, R_{GEN} = 25Ω, I_D = 6.0A, V_{GS} = 10V,	$t_{d(on)}$	--	25	--	ns
Turn-On Rise Time		t_r	--	57	--	
Turn-Off Delay Time		$t_{d(off)}$	--	83	--	
Turn-Off Fall Time		t_f	--	61	--	
Source-Drain Diode (Note 4)						
Forward On Voltage	I_S = 3.0A, V_{GS} = 0V	V_{SD}	--	--	1.5	V
Reverse Recovery Time	I_S =1A dI$_F$/dt = 100A/μs	t_{rr}	--	213	--	ns
Reverse Recovery Charge		Q_{rr}	--	2480	--	nC
Source Current	Integral reverse diode in the MOSFET	I_S	--	--	7	A
Source Current (Pulse)		I_{SM}	--	--	28	A

Notes:

1. Current limited by package
2. Pulse width limited by the maximum junction temperature
3. L = 12mH, I_{AS} = 5.0A, V_{DD} = 50V, R_G = 25Ω, Starting T_J = 25°C
   100% Eas Test Condition: L = 12mH, I_{AS} = 2.5A, V_{DD} = 50V, R_G = 25Ω, Starting T_J = 25°C
4. Pulse test: PW ≤ 300μs, duty cycle ≤ 2%
5. For DESIGN AID ONLY, not subject to production testing.
6. Switching time is essentially independent of operating temperature.

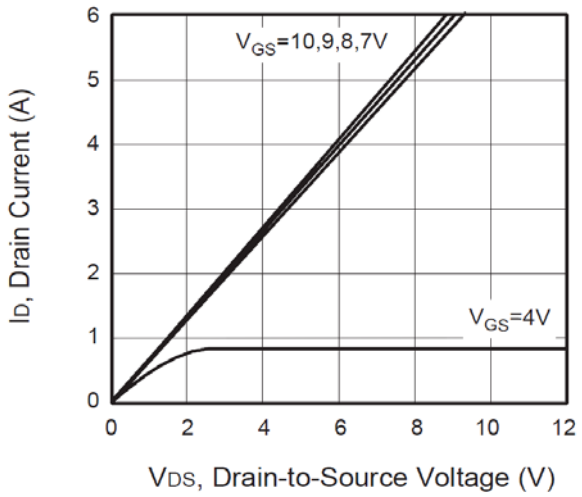
ORDERING INFORMATION

PART NO.	PACKAGE	PACKING
TSM7N65ACI C0G	ITO-220	50pcs / Tube

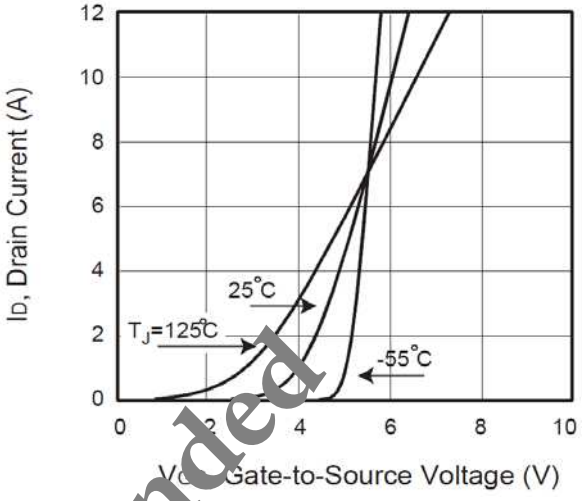
CHARACTERISTICS CURVES

(T_C = 25°C unless otherwise noted)

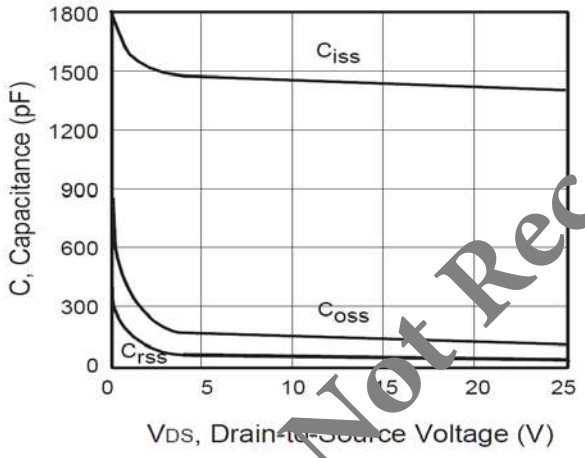
Output Characteristics



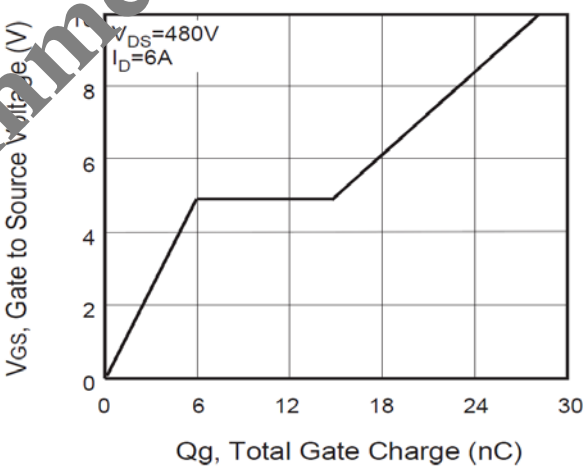
Transfer Characteristics



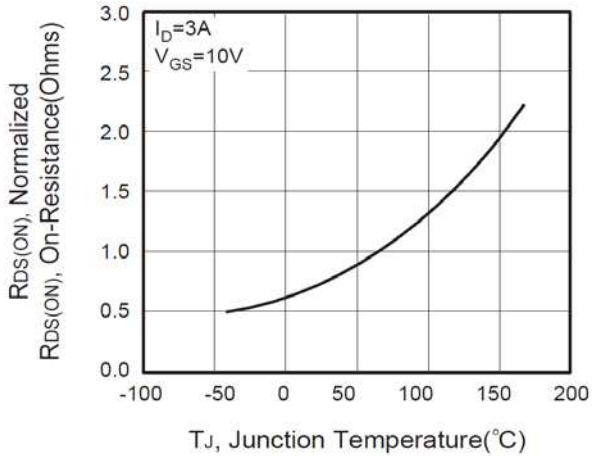
Capacitance



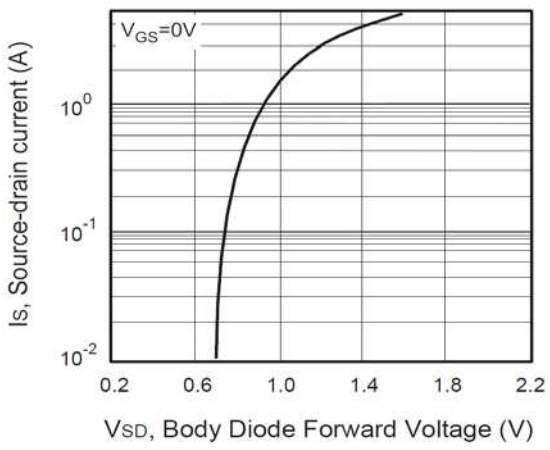
Gate Charge



On-Resistance vs. Junction Temperature



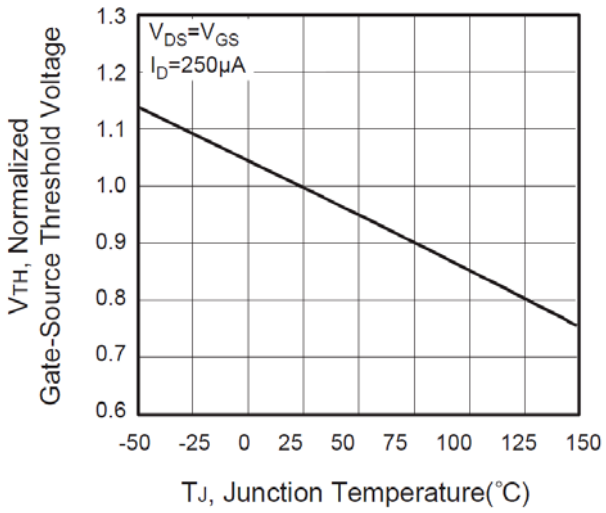
Source-Drain Diode Forward Voltage



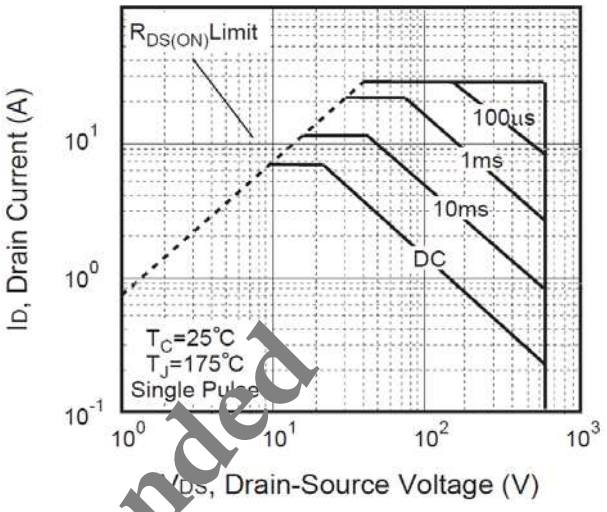
CHARACTERISTICS CURVES

(T_C = 25°C unless otherwise noted)

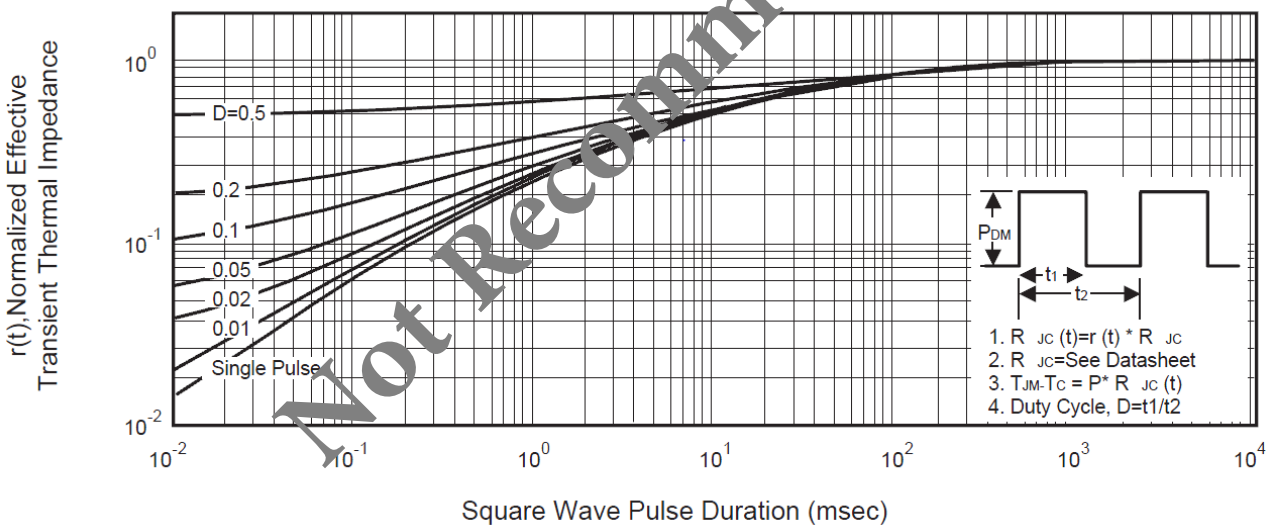
Threshold Voltage vs. Junction Temperature



Maximum Safe Operating Area

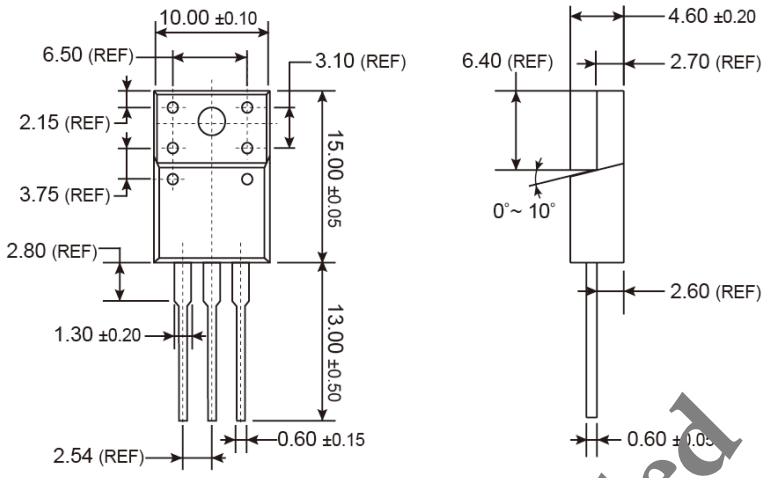


Normalized Thermal Transient Impedance Curve

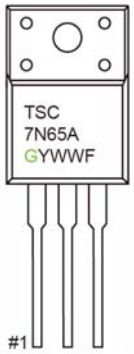


PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)

ITO-220



MARKING DIAGRAM



G = Halogen Free
Y = Year Code
WW = Week Code (01~52)
F = Factory Code

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